

SS2PH9 & SS2PH10

Vishay General Semiconductor

# **High-Voltage Surface Mount Schottky Barrier Rectifiers**

High Barrier Technology for Improved High Temperature Performance



SHA

DO-220AA (SMP)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2.0 A			
V <sub>RRM</sub>	90 V, 100 V			
I <sub>FSM</sub>	50 A			
E <sub>AS</sub>	11.25 mJ			
V <sub>F</sub> at I <sub>F</sub> = 1.0 A	0.62 V			
I <sub>R</sub> max.	1.0 μA			
T <sub>J</sub> max.	175 °C			

### FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

### **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: Color band denotes the cathode end

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SS2PH9	SS2PH10	UNIT
Device marking code		29	210	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	90	100	V
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub>	2.0		А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50		А
Non-repetitive avalanche energy at $T_J = 25 \degree C$ , $I_{AS} = 1.5 \mbox{ A}$ , $L = 10 \mbox{ mH}$	E <sub>AS</sub>	11.25		mJ
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10000		V/µs
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175		°C

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \degree C$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 2.0 A, I <sub>F</sub> = 2.0 A,	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.77 0.62	0.80 0.66	V
Maximum DC reverse current	rated $V_R^{(1)}$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	0.1 60	1.0 500	μΑ
Typical junction capacitance	at 4.0 V, 1 MHz		CJ	65	-	pF

#### Note:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

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THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	SS2PH9	SS2PH10	UNIT			
Typical thermal resistance <sup>(1)</sup>	R <sub>θJA</sub> R <sub>θJL</sub> B <sub>θ.IC</sub>	110 15 25		°C/W			

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 15 x 15 mm copper pad areas. R<sub>0JL</sub> is measured at the terminal of cathode band.  $\mathsf{R}_{\theta JC}$  is measured at the top center of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS2PH9-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
SS2PH9-E3/85A	0.024	85A	10000	13" diameter plastic tape and reel		
SS2PH9HE3/84A <sup>(1)</sup>	0.024	84A	3000	7" diameter plastic tape and reel		
SS2PH9HE3/85A (1)	0.024	85A	10000	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

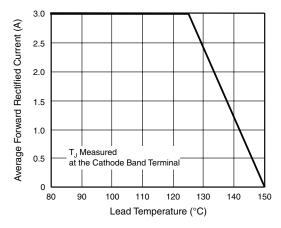


Figure 1. Forward Current Derating Curve

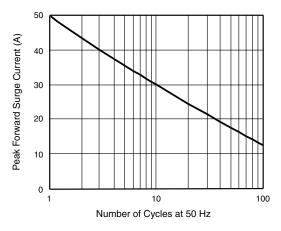


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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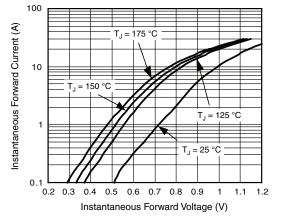


Figure 3. Typical Instantaneous Forward Characteristics

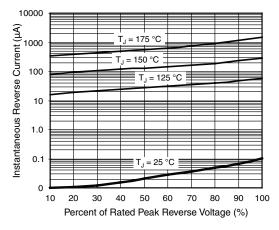


Figure 4. Typical Reverse Leakage Characteristics

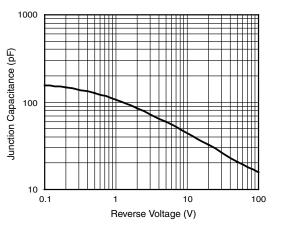
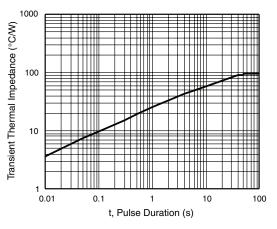
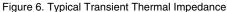
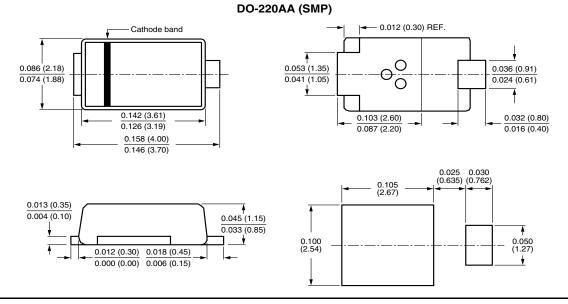


Figure 5. Typical Junction Capacitance





### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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